

SE80PWB, SE80PWD, SE80PWG, SE80PWJ

Vishay General Semiconductor

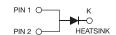
AUTOMOTIVE

COMPLIANT

HALOGEN FREE

Surface-Mount ESD Capability Rectifier





LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	8 A				
V _{RRM}	100 V, 200 V, 400 V, 600 V				
I _{FSM}	110 A				
V _F at I _F = 8 A (T _A = 125 °C)	0.92 V				
T _J max.	175 °C				
Package	SlimDPAK (TO-252AE)				
Circuit configurations	Single				

FEATURES

- · Very low profile typical height of 1.3 mm
- · Ideal for automated placement
- · Oxide planar chip junction
- Low forward voltage drop
- ESD capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

General purpose, power line polarity protection, in both industry and automotive applications.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SE80PWB	SE80PWD	SE80PWG	SE80PWJ	UNIT
Device marking code		SE80PWB	SE80PWD	SE80PWG	SE80PWJ	
Maximum repetitive peak reverse voltage	V_{RRM}	100	200	400	600	V
Maximum average forward rectified current (Fig. 1)	I _{F(AV)} (1)	8.0				А
Maximum average forward rectified current (Fig. 1)	I _{F(AV)} (2)	3.5				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	110			Α	
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +175				°C

Notes

- (1) With infinite heatsink
- (2) Free air, mounted on recommended copper pad area



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum Instantaneous forward voltage	$I_F = 4.0 A$	T 05 °C		0.93	-		
	I _F = 8.0 A T _A = 25 °C	V _E (1)	1.01	1.12	V		
	I _F = 4.0 A	T _A = 125 °C	VF (*)	0.82	-	V	
	I _F = 8.0 A			0.92	1.07		
Reverse current	Rated V _R	T _A = 25 °C	I _R ⁽²⁾	-	15		
	$T_A = 125 ^{\circ}\text{C}$	'R '-'	19	150	- μA		
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	2400	-	ns	
Typical junction capacitance	4.0 V, 1 MHz		CJ	58	-	pF	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL SE80PWB SE80PWD SE80PWG SE80PWJ UNIT				UNIT	
Turnical they made vaciation as	R ₀ JA (1)(2)	60				°C/W
Typical thermal resistance $R_{\theta JM}^{(3)}$		2.2				C/VV

Notes

- $^{(1)}$ The heat generated must be less than thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- (2) Free air, mounted on recommended copper pad area; thermal resistance R_{BJA} junction to ambient
- $^{(3)}$ Mounted on infinite heat sink; thermal resistance $R_{\theta JM}$ junction-to-mount

IMMUNITY TO ELECTRICAL STATIC DISCHARGE TO THE FOLLOWING STANDARDS (T _A = 25 $^{\circ}$ C unless otherwise noted)						
STANDARD TEST TYPE TEST CONDITIONS SYMBOL CLASS VALUE				VALUE		
AEC-Q101-001	Human body model (contact mode) $C = 100$ pF, $R = 1.5$ kΩ V_C H3B > 8 kV					

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SE80PWJ-M3/I	0.20	I	4500	13" diameter plastic tape and reel		
SE80PWJHM3/I (1)	0.20	I	4500	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

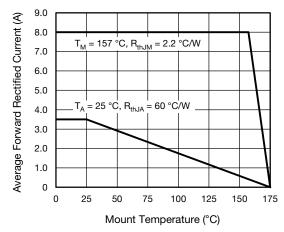


Fig. 1 - Maximum Forward Current Derating Curve

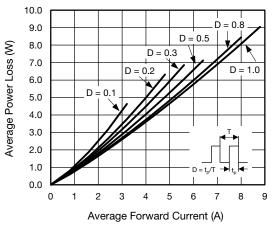


Fig. 2 - Forward Power Loss Characteristics

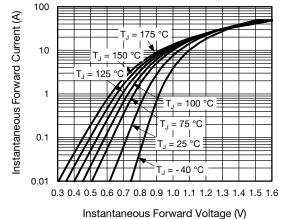


Fig. 3 - Typical Instantaneous Forward Characteristics

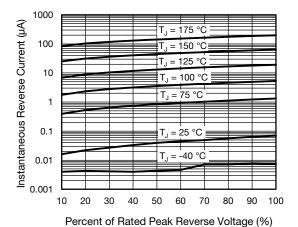


Fig. 4 - Typical Reverse Leakage Characteristics

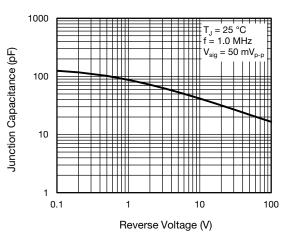


Fig. 5 - Typical Junction Capacitance

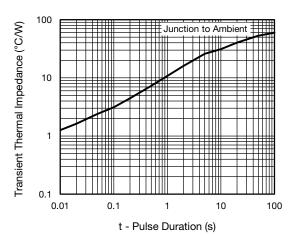


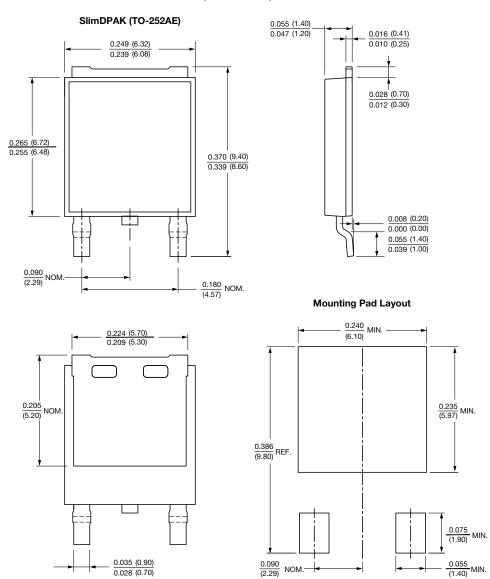
Fig. 6 - Typical Transient Thermal Impedance



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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